# 2SB0943 (2SB943)

### Silicon PNP epitaxial planar type

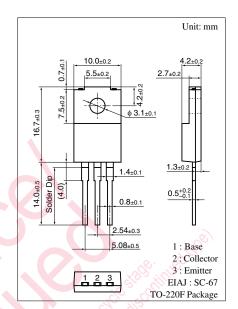
For power switching Complementary to 2SD1268

#### ■ Features

- ullet Low collector to emitter saturation voltage  $V_{CE(sat)}$
- ullet Satisfactory linearity of forward current transfer ratio  $h_{FE}$
- Large collector current I<sub>C</sub>
- Full-pack package which can be installed to the heat sink with one screw

#### ■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit	
Collector to base voltage		$V_{CBO}$	-130	V	
Collector to emitter voltage		$V_{CEO}$	-80	V	
Emitter to base voltage		$V_{EBO}$	-7	V	
Peak collector current		$I_{CP}$	-6	A	
Collector current		$I_{C}$	-3	A	
Collector power	$T_C = 25^{\circ}C$	P <sub>C</sub>	30	W	
dissipation	$T_a = 25^{\circ}C$		2		
Junction temperature		Tj	150	°C	
Storage temperature		T <sub>stg</sub>	-55 to +150	°C	



#### ■ Electrical Characteristics $T_C = 25$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = -100 \text{ V}, I_{E} = 0$			-10	μΑ
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$			-50	μΑ
Collector to emitter voltage	V <sub>CEO</sub>	$I_C = -10 \text{ mA}, I_B = 0$	-80			V
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CE} = -2 \text{ V}, I_{C} = -0.1 \text{ A}$	45			
	h <sub>FE2</sub> *	$V_{CE} = -2 \text{ V}, I_C = -0.5 \text{ A}$	90		260	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -2 A, I_B = -0.1 A$			- 0.5	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = -2 \text{ A}, I_B = -0.1 \text{ A}$			-1.5	V
Transition frequency	$f_T$	$V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t <sub>on</sub>	$I_C = -0.5 \text{ A}, I_{B1} = -50 \text{ mA}, I_{B2} = 50 \text{ mA}$		0.3		μs
Storage time	t <sub>stg</sub>			1.1		μs
Fall time	t <sub>f</sub>			0.3		μs

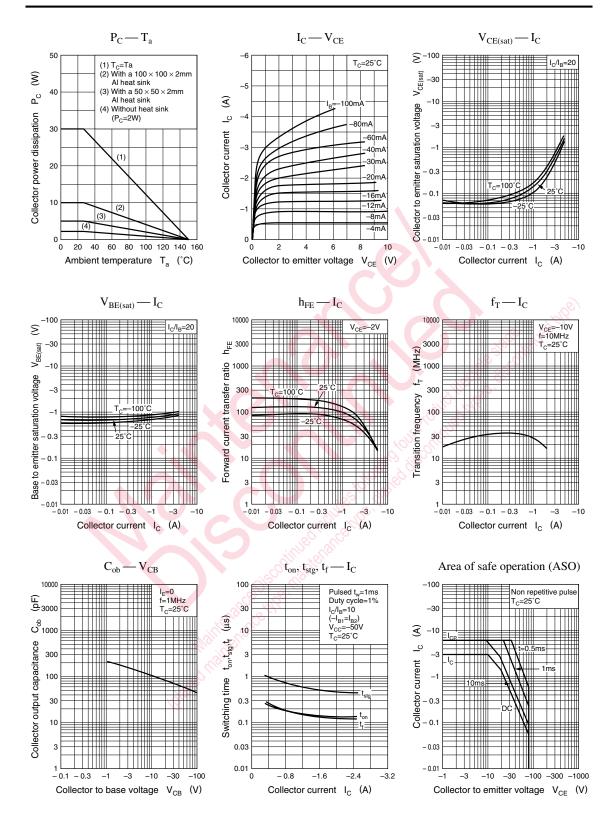
Note) \*: Rank classification

Rank	Q	Р
h <sub>FE2</sub>	90 to 180	130 to 260

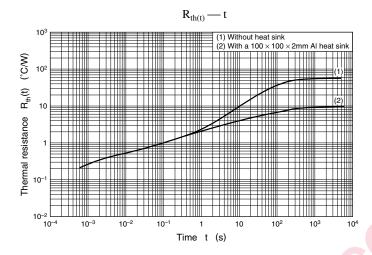
Note.) The Part number in the Parenthesis shows conventional part number.

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2SB0943 Power Transistors



Power Transistors 2SB0943



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